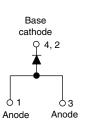
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Schottky Rectifier, 5.5 A





D-PAK	(TO-252AA)
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PRODUCT SUMMARY					
Package	D-PAK (TO-252AA)				
I _{F(AV)}	5.5 A				
V _R	100 V				
V _F at I _F	See Electrical table				
I _{RM}	4 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Single die				
E _{AS}	6 mJ				

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Popular D-PAK outline
- Small foot print, surface mountable
- High frequency operation
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-50WQ10FNHM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	5.5	A				
V _{RRM}		100	V				
I _{FSM}	$t_p = 5 \ \mu s \ sine$	330	A				
V _F	5 A _{pk} , T _J = 125 °C	0.63	V				
TJ	Range	- 40 to 150	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-50WQ10FNHM3	UNITS			
Maximum DC reverse voltage	V _R	100	V			
Maximum working peak reverse voltage	V _{RWM}	100	v			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 135 °C	5.5				
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	330	Α		
See fig. 7			V _{RRM} applied	110			
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 0.5 A, L = 40 mH		6.0	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 0.5		0.5	А		

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e3 RoHS COMPLIANT HALOGEN

FREE



VS-50WQ10FNHM3

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ELECTRICAL	SPECIFICATIONS
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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS VALUES				
		5 A	T.I = 25 °C	0.77	V	
Maximum forward voltage drop	V _{EM} ⁽¹⁾	10 A	1j=25 0	0.91		
See fig. 1	VFM (*)	5 A	T. = 125 °C	0.63		
		10 A	1j = 125 C	0.74		
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C		1	mA	
See fig. 2	IRM (')	T _J = 125 °C	$V_R = Rated V_R$	4		
Threshold voltage	V _{F(TO)}			0.47	V	
Forward slope resistance	r _t	T _J =T _J maximum 21.46 r				
Typical junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C 183 pF				
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 5.0 nH				

Note

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 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	3.0	°C/W	
Approximate weight			0.3	g	
Approximate weight			0.01	oz.	
Marking device		Case style D-PAK	50WQ	10FNH	

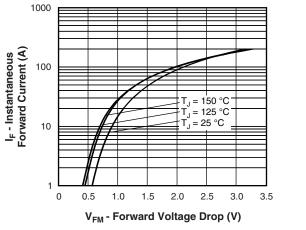
Note

(1)

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

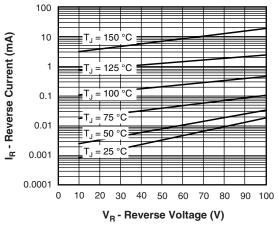
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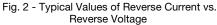
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Fig. 1 - Maximum Forward Voltage Drop Characteristics





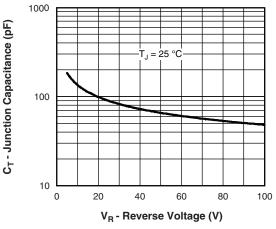


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

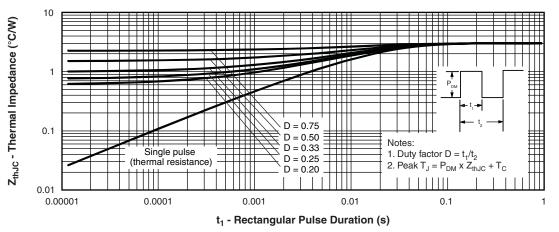


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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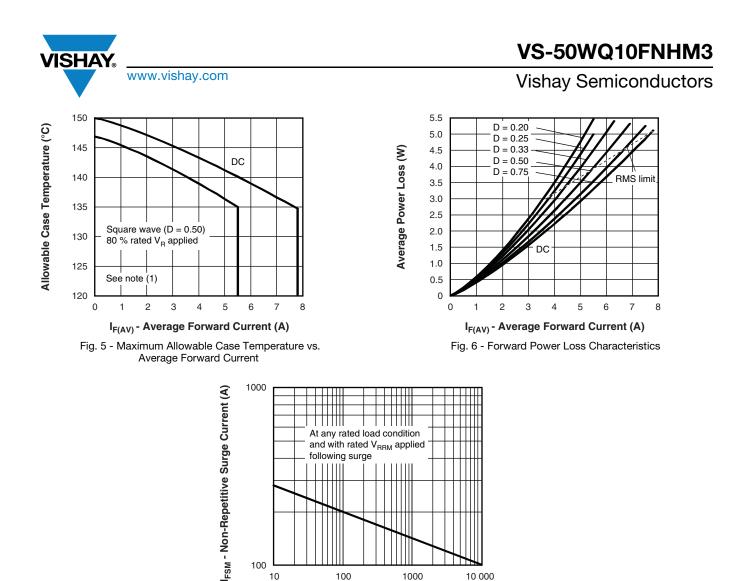




Fig. 7 - Maximum Non-Repetitive Surge Current

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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ORDERING INFORMATION TABLE

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VISHAY

Device code	VS-	50	w	Q	10	FN	TRL	н	М3
		(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)
		\bigcirc							
	1	- Visl	nay Sen	niconduo	ctors pro	oduct			
	2	- Cur	rent rati	ng (5.5	A)				
	3	- Pac	kage id	entifier:					
		W =	D-PAK	(
	4	- Sch	ottky "C)" series					
	5	- Vol	tage rati	ing (10 =	= 100 V)				
	6	- FN	= TO-2	52AA (D	-PAK)				
		- • N	one = T	ube					
		• TI	R = Tap	e and re	el				
		• TI	RL = Ta	pe and r	eel (left	oriente	d)		
		• TI	RR = Ta	pe and	reel (rig	ht orien	ted)		
	8	- H=	AEC-Q	101 qua	alified				
	9	- Env	vironme	ntal digit					
		M3	= Halog	jen-free,	RoHS-	complia	nt, and	termina	tions lea

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-50WQ10FNHM3	75	3000	Antistatic plastic tube				
VS-50WQ10FNTRHM3	2000	2000	13" diameter reel				
VS-50WQ10FNTRRHM3	3000	3000	13" diameter reel				
VS-50WQ10FNTRLHM3	3000	3000	13" diameter reel				

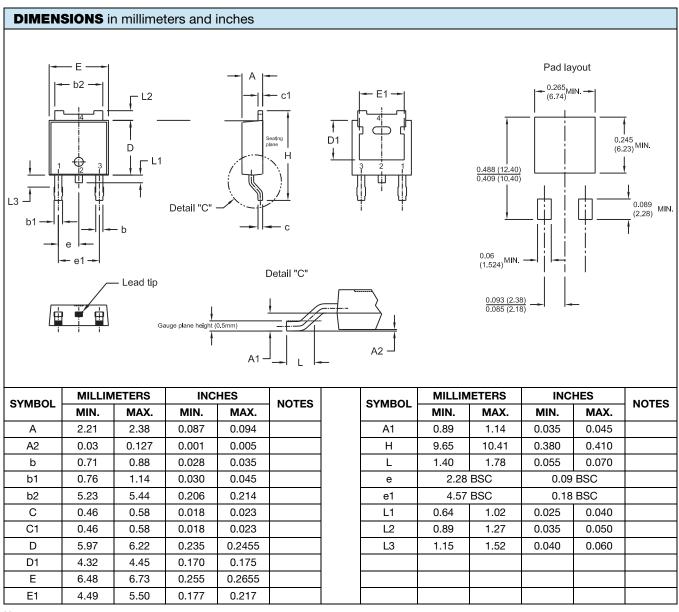
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95519				
Part marking information	www.vishay.com/doc?95518				
Packaging information	www.vishay.com/doc?95033				

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D-PAK (TO-252AA)



Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L3 only for reference

⁽³⁾ Dimension D1, E1, L2 and b2 establish a minimum mounting surface for thermal pad

⁽⁴⁾ Dimensions D and E do not include mold flash.

⁽⁵⁾ Outline conforms to JEDEC outline TO-252AA

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